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Customer No.: 31561
Docket No.: 13184-US-PA
Application No.: 10/710,696

AMENDMENTS

In The Claims

1. (currently amended) A photoelectric device grinding process, comprising the steps of:
 - providing a wafer having a plurality of chip units thereon, wherein the surface of each chip unit has at least a photoelectric device;
 - providing an amount of glue ~~[[having]]~~with a plurality of spacers ~~[[surrounded by the glue]]~~ therein;
 - attaching a dielectric substrate over the photoelectric device on the surface of the wafer through the glue, wherein the glue and the spacers are disposed between the dielectric substrate and the wafer and both of the glue and the spacers are directly contacted with the dielectric substrate and the wafer, such that the spacers maintain a constant gap between the dielectric substrate and the wafer and the glue surrounds the spacers at a side surface of not contacting the dielectric substrate and the wafer; and
 - after attaching the dielectric substrate over the photoelectric device on the surface of the wafer, grinding the surface of the dielectric substrate away from the wafer or the surface of the wafer away from the dielectric substrate.
2. (original) The photoelectric device grinding process of claim 1, wherein the photoelectric device comprises an image sensor.
3. (original) The photoelectric device grinding process of claim 1, wherein the photoelectric device comprises a micro-mechanical structure.

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4. (original) The photoelectric device grinding process of claim 3, wherein the micro-mechanical structure protrudes from the surface of the wafer by a height smaller than the gap between the dielectric substrate and the wafer.

5. (original) The photoelectric device grinding process of claim 1, wherein the glue comprises ultraviolet cured plastic.

6. (original) The photoelectric device grinding process of claim 1, wherein the material constituting the spacers comprises silicon oxide.

7. (original) The photoelectric device grinding process of claim 1, wherein the step of grinding the dielectric substrate or the wafer comprises mechanical grinding.

8. (original) The photoelectric device grinding process of claim 1, wherein the dielectric substrate comprises a glass substrate or a silicon substrate.

9. (original) The photoelectric device grinding process of claim 1, wherein the glue, each chip unit and the dielectric substrate together form at least a sealed chamber such that the photoelectric device is enclosed within the sealed chamber.

10. (currently amended) A device grinding process, comprising the steps of:
providing a wafer having a plurality of chip units thereon, wherein the surface of each chip unit has at least a device;

attaching a dielectric substrate over the device on the surface of the wafer by an amount of glue such that a constant gap is maintained between the dielectric substrate and the wafer, wherein the glue ~~[[comprises]]~~ containing a plurality of spacers ~~[[surrounded by the glue]]~~ therein to hold the constant gap; and